
	<p>SI1024X-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI1024X-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 0.485A SC89-6</p> <p>Datenblätter:  SI1024X-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 79794 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1024X-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 0.485A SC89-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	79794 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	485mA
Rds On (Max) @ Id, Vgs	700 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI1024X-T1-GE3 ist neu im Original, Suche SI1024X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1024X-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1024X-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1024X-T1 VISHAY SI1024X-T1 VISHAY</p>	 <p>SI1024X-T1-GE3 VISHAY SI1024X-T1-GE3 VISHAY</p>	 <p>SI1024X-T1-E3 SOT563 VISHAY SI1024X-T1-E3 SOT563 VISHAY</p>	 <p>SI1024X-T1-E3 Vishay / Siliconix MOSFET 2N-CH 20V 0.485A SOT563F</p>
 <p>SI1024X-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 0.485A SOT563F</p>	 <p>SI1024-T1 VISHAY SI1024-T1 VISHAY</p>	 <p>SI1024X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 0.485A SC89-6</p>	 <p>SI1025-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>

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|---|--|--|---|---|
|  SI1016X-T1-E3 |  SI1016X-T1-E3 |  SI1016X-T1-GE3 |  SI1016X-T1-GE3 |  SI1016X2-T1-GE3 |
|  SI1021R-T1 |  SI1021R-T1-E3 |  SI1021R-T1-E3 |  SI1022R-T1 |  SI1022R-T1-E3 |
|  SI1022R-T1-E3 |  SI1022R-T1-GE3 |  SI1022R-T1-GE3 |  SI1022R-TI-E3 |  SI1023CX-T1-GE3 |
|  SI1023CX-T1-GE3 |  SI1023X-T1 |  SI1023X-T1-E3 |  SI1023X-T1-E3 |  SI1023X-T1-GE3 |
|  SI1023X-T1-GE3 |  SI1024-T1 |  SI1024X-T1 |  SI1024X-T1-E3 |  SI1024X-T1-E3 |
|  SI1024X-T1-GE3 |  SI1024X-TI-GE3 |  SI1025X-T1 |  SI1025X-T1-E3 |  SI1025X-T1-E3 |
|  SI1026X-T1 |  SI1026X-T1-E3 |  SI1026X-T1-E3 |  SI1026X-T1-GE3 |  SI1026X-T1-GE3 |
|  SI1028X-T1-GE3 |  SI1028X-T1-GE3 |  SI1029X-T1-GE3 |  SI1029X-T1-GE3 |  SI1031R-T1 |
|  SI1031R-T1-E3 |  SI1031R-T1-E3 |  SI1031R-T1-GE3 |  SI1031R-T1-GE3 |  SI1031X-T1 |
|  SI1031X-T1-E3 |  SI1031X-T1-E3 |  SI1031X-T1-GE3 |  SI1031X-T1-GE3 |  SI1032R-T1 |

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